

SMDJ-H Series

General Information

The SMDJ-H series is designed to protect voltage sensitive components from high voltage, high energy transients. They have excellent clamping capability, high surge capability, low zener impedance and fast response time. The SMD-H series is supplied in YINT Semiconductor's exclusive, cost-effective, highly reliable and is ideally suited for use in communication systems, automotive, numerical controls, process controls, medical equipment, business machines, power supplies and many other industrial/consumer Applications.



Molded plastic glass passivated junction.

Features

- Case: DO-214AB/SMC
- For surface mounted applications in order to optimize board space.
- Polarity: Color band denoted positive end (cathode) except Bidirectional.
- Typical failure mode is short from over-specified voltage or current
- High Temperature soldering:260°C/10 seconds at terminals.
- Terminal: Solder plated, solderable per MIL-STD-750, Method 2026.
- AEC-Q101 qualified

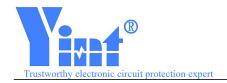
Applications

TVS devices are ideal for the protection of I/O Interfaces, V_{CC} bus and other vulnerable circuits used in Telecom, Computer, Industrial and Consumer electronic applications

Electrical Characteristics (@ TA = 25° C Unless Otherwise Noted)

Parameter	Symbol	Value	Unit
Minimum Peak Pulse Power Dissipation (T = 1 ms) (note1 note 2)	P _{PK}	3000	Watts
Peak Forward Surge Current			
8.3 ms Single Half Sine Wave Superimposed on Rated Load	I _{FSM}	300	Amps
(JEDEC Method) (Note 3)			
Steady State Power Dissipation @ TL = 75 °C	P _{M(AV)}	6.5	Watts
Maximum Instantaneous Forward Voltage @ I PP = 50 A	VF	3.5/5	Volts
(For Unidirectional Units Only)(note4 Note 5)	VF	3.5/5	VOILS
Operating Temperature Range	TJ	-55 to +150	°C
Storage Temperature Range	T _{STG}	-55 to +150	°C

- 1. Non-repetitive current pulse, per Pulse Waveform graph and derated above $T_A = 25$ °C per Pulse Derating Curve.
- 2. Thermal Resistance Junction to Lead.
- 3. 8.3 ms Single Half-Sine Wave duty cycle = 4 pulses maximum per minute (unidirectional units only).
- 4. Single Phase, Half Wave, 60 Hz, resistive or inductive load. For capacitive load, derate current by 20 %.
- 5. V_F <3.5V for V_{BR} < 200V and V_F <5.0V for V_{BR} > 201V.



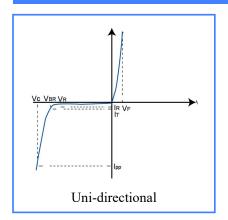
Electrical Characteristics (T _A = 25 °C unless otherwise noted)										
				Reverse	Break	down		Maximum	Maximum	Maximum
Part	Part	MARKING		Stand off	Voltage V _{BR}		Test	Reverse	Maximum	Clamping
Number	Number			Voltage	(Volts)@I _⊺		Current	Leakage	Peak Pulse	Voltage
(Bi)	(Uni)			V_{R}	NAIS NA	March	I _⊤ (mA)	I _R	Current	Vc
		BI	UNI	(Volts)	Min .V	Max .V		@ V _R (μA)	Ipp(A)	@I pp(V)
SMDJ5.0CA-H	SMDJ5.0A-H	DDEH	RDEH	5.0	6.40	7.00	10	800	326.1	9.2
SMDJ6.0CA-H	SMDJ6.0A-H	DDGH	RDGH	6.0	6.67	7.37	10	800	291.3	10.3
SMDJ 6.5CA-H	SMDJ 6.5A-H	DDKH	RDKH	6.5	7.22	7.98	10	500	267.9	11.2
SMDJ7.0 CA-H	SMDJ7.0 A-H	DDMH	PDMH	7.0	7.78	8.60	10	200	250.0	12.0
SMDJ 7.5CA-H	SMDJ 7.5A-H	DDPH	PDPH	7.5	8.33	9.21	1	100	232.6	12.9
SMDJ 8.0CA-H	SMDJ 8.0A-H	DDRH	PDRH	8.0	8.89	9.83	1	50	220.6	13.6
SMDJ8.5 CA-H	SMDJ8.5 A-H	DDTH	PDTH	8.5	9.44	10.40	1	20	208.3	14.4
SMDJ9.0 CA-H	SMDJ9.0 A-H	DDVH	PDVH	9.0	10.00	11.10	1	10	194.8	15.4
SMDJ10CA-H	SMDJ10A-H	DDXH	PDXH	10.0	11.10	12.30	1	5	176.5	17.0
SMDJ11CA-H	SMDJ11A-H	DDZH	PDZH	11.0	12.20	13.50	1	2	164.8	18.2
SMDJ12CA-H	SMDJ12A-H	DEEH	PEEH	12.0	13.30	14.70	1	2	150.8	19.9
SMDJ13CA-H	SMDJ13A-H	DEGH	PEGH	13.0	14.40	15.90	1	2	139.5	21.5
SMDJ14CA-H	SMDJ14A-H	DEKH	PEKH	14.0	15.60	17.20	1	2	129.3	23.2
SMDJ15CA-H	SMDJ15A-H	DEMH	PEMH	15.0	16.70	18.50	1	2	123.0	24.4
SMDJ16CA-H	SMDJ16A-H	DEPH	PEPH	16.0	17.80	19.70	1	2	115.4	26.0
SMDJ17CA-H	SMDJ17A-H	DERH	PERH	17.0	18.90	20.90	1	2	108.7	27.6
SMDJ18CA-H	SMDJ18A-H	DETH	PETH	18.0	20.00	22.10	1	2	102.7	29.2
SMDJ20CA-H	SMDJ20A-H	DEVH	PEVH	20.0	22.20	24.50	1	2	92.6	32.4
SMDJ22CA-H	SMDJ22A-H	DEXH	PEXH	22.0	24.40	26.90	1	2	84.5	35.5
SMDJ24CA-H	SMDJ24A-H	DEZH	PEZH	24.0	26.70	29.50	1	2	77.1	38.9
SMDJ26CA-H	SMDJ26A-H	DFEH	PFEH	26.0	28.90	31.90	1	2	71.3	42.1
SMDJ28CA-H	SMDJ28A-H	DFGH	PFGH	28.0	31.10	34.40	1	2	66.1	45.4
SMDJ30CA-H	SMDJ30A-H	DFKH	PFKH	30.0	33.30	36.80	1	2	62.0	48.4
SMDJ33CA-H	SMDJ33A-H	DFMH	PFMH	33.0	36.70	40.60	1	2	56.3	53.3
SMDJ36CA-H	SMDJ36A-H	DFPH	PFPH	36.0	40.00	44.20	1	2	51.6	58.1
SMDJ40CA-H	SMDJ40A-H	DFRH	PFRH	40.0	44.40	49.10	1	2	46.5	64.5
SMDJ43CA-H	SMDJ43A-H	DFTH	PFTH	43.0	47.80	52.80	1	2	43.2	69.4
SMDJ45CA-H	SMDJ45A-H	DFVH	PFVH	45.0	50.00	55.30	1	2	41.3	72.7
SMDJ48CA-H	SMDJ48A-H	DFXH	PFXH	48.0	53.30	58.90	1	2	38.8	77.4
SMDJ51CA-H	SMDJ51A-H	DFZH	PFZH	51.0	56.70	62.70	1	2	36.4	82.4
SMDJ54CA-H	SMDJ54A-H	DGEH	RGEH	54.0	60.00	66.30	1	2	34.4	87.1
SMDJ58CA-H	SMDJ58A-H	DGGH	PGGH	58.0	64.40	71.20	1	2	32.1	93.6
SMDJ60CA-H	SMDJ60A-H	DGKH	PGKH	60.0	66.70	73.70	1	2	31.0	96.8
SMDJ64CA-H	SMDJ64A-H	DGMH	PGMH	64.0	71.10	78.60	1	2	29.1	103.0
SMDJ70CA-H	SMDJ70A-H	DGPH	PGPH	70.0	77.80	86.00	1	2	26.5	113.0
SMDJ75CA-H	SMDJ75A-H	DGRH	PGRH	75.0	83.30	92.10	1	2	24.8	121.0
SMDJ78CA-H	SMDJ78A-H	DGTH	PGTH	78.0	86.70	95.80	1	2	23.8	126.0

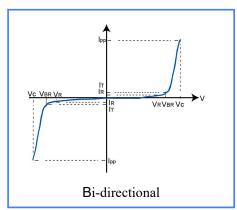
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Automotive and	High Relia	ibility TVS	Diodes
Surface Mount -	3000W >	SMDI-H	Series

Trustworthy electron	ic circuit protection	гелрен				Duriue	C IVIOUIII	300011	DIVIDO	11 Delles
SMDJ85CA-H	SMDJ85A-H	DGVH	PGVH	85.0	94.40	104.0	1	2	21.9	137.0
SMDJ90CA-H	SMDJ90A-H	DGXH	PGXH	90.0	100.0	111.0	1	2	20.5	146.0
SMDJ100CA-H	SMDJ100A-H	DGZH	PGZH	100.0	111.0	123.0	1	2	18.5	162.0
SMDJ110CA-H	SMDJ110A-H	DHEH	PHEH	110.0	122.0	135.0	1	2	16.9	177.0
SMDJ120CA-H	SMDJ120A-H	DHGH	PHGH	120.0	133.0	147.0	1	2	15.5	193.0
SMDJ130CA-H	SMDJ130A-H	DHKH	PHKH	130.0	144.0	159.0	1	2	14.4	209.0
SMDJ150CA-H	SMDJ150A-H	DHMH	PHMH	150.0	167.0	185.0	1	2	12.3	243.0
SMDJ160CA-H	SMDJ160A-H	DHPH	PHPH	160.0	178.0	197.0	1	2	11.6	259.0
SMDJ170CA-H	SMDJ170A-H	DHRH	PHRH	170.0	189.0	209.0	1	2	10.9	275.0
SMDJ180CA-H	SMDJ180A-H	IHTH	HHTH	180.0	201.0	222.0	1	2	10.3	292.0
SMDJ190CA-H	SMDJ190A-H	IHVH	HHVH	190.0	211.0	233.0	1	2	9.7	308.0
SMDJ200CA-H	SMDJ200A-H	IHXH	ННХН	200.0	224.0	247.0	1	2	9.3	324.0
SMDJ210CA-H	SMDJ210A-H	IHZH	HHZH	210.0	237.0	263.0	1	2	8.8	340.0
SMDJ220CA-H	SMDJ220A-H	IIIEH	HIEH	220.0	246.0	272.0	1	2	8.4	356.0

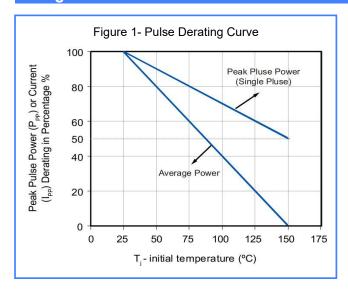
I-V Curve Characteristics

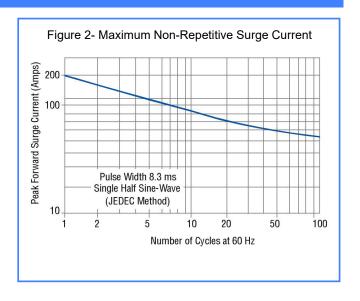




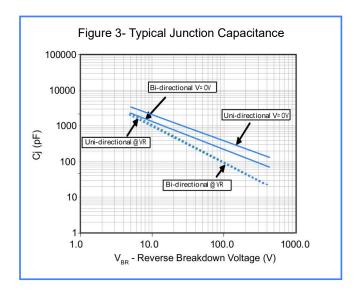
Symbol	Parameter
I _{PP}	Maximum Reverse Peak
	Pulse Current
Vc	Clamping Voltage @ IPP
V RWM	Working Peak Reverse
	Voltage
I _R	Maximum Reverse
	Leakage Current @V RWM
V BR	Breakdown Voltage @ I⊤
Ι _Τ	Test Current

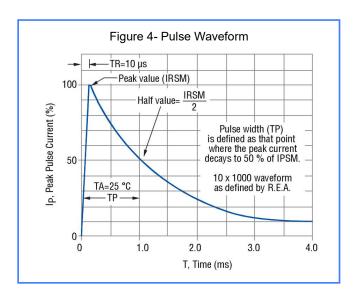
Rating & Characteristic Curves

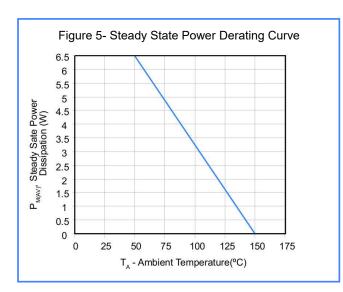


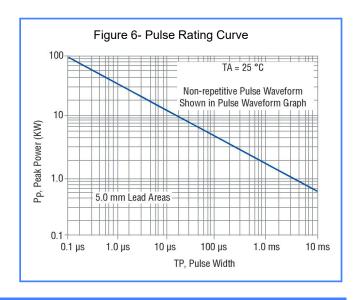






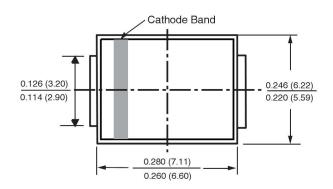




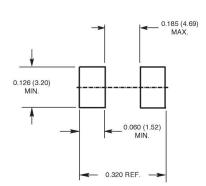


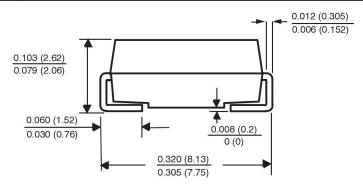
PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

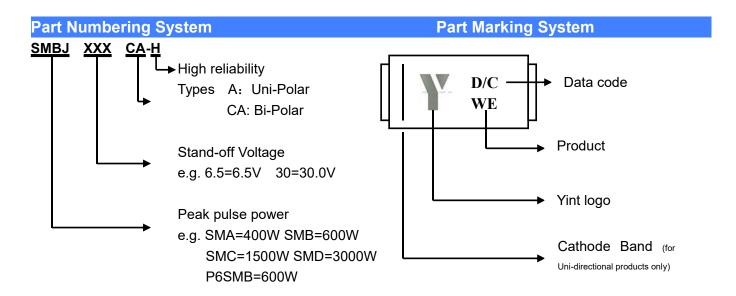
DO-214AB(SMC)



Mounting Pad Layout







Disclaimer

Specifications are subject to change without notice.

The device characteristics and parameters in this data sheet can and do vary in different applications and actual device performance may vary over time.

Users should verify actual device performance in their specific applications.